## 2020년 2월 14일(금), 15:45~17:30 Room B (에메랄드 II+III, 5층)

## F. Silicon and Group-IV Devices and Integration Technology 분과 [FB3-F] Nano-electromechanical and 3D Integration Technology

FB3-F-1 15:45~16:00	Island-style Monolithic Three-dimensional (M3D) CMOS–NEM Reconfigurable Logic (RL) Circuits Hyug Su Kwon, Ji Wang Ko, and Woo Young Choi Department of Electronic Engineering, Sogang University
FB3-F-2 16:00~16:15	<b>Novel Release Mechanism of Nanoelectromechanical Memory Switches</b> Gwangryeol Baek and Woo Young Choi <i>Department of Electronic Engineering, Sogang University</i>
FB3-F-3 16:15~16:30	Dynamic Slingshot Pull-in Operation of Nanoelectromechanical (NEM) Memory Switches for Low Operating Voltage Min Hee Kang and Woo Young Choi Department of Electronic Engineering, Sogang University
FB3-F-4 16:30~16:45	Low-power Nanoelectromechanical (NEM) Device with HfO <sub>2</sub> -based Ferroelectric Capacitor Shinhee Kim <sup>1</sup> , Jae Yeon Park <sup>1</sup> , Hyug Su Kwon <sup>2</sup> , Woo Young Choi <sup>2</sup> , and Sangwan Kim <sup>1</sup> <sup>1</sup> Department of Electrical and Computer Engineering, Ajou University, <sup>2</sup> Department of Electrical Engineering, Sogang University
FB3-F-5 16:45~17:00	피드백 전계 효과 트랜지스터를 활용한 적층형 3차원 집적회로 특성 관찰 Jong Hyeok Oh and Yun Seop Yu Department of Electrical, Electronic and Control Engineering, Hankyong National University
FB3-F-6 17:00~17:15	<b>3D NAND 제작을 위한 비인산계 식각액의 선택적 Si₃N₄ 식각 공정</b> 손창진, 임상우 <i>Department of Chemical and Biomolecular Engineering, Yonsei University</i>
FB3-F-7 17:15~17:30	Interface Charge Effects of Monolithic 3D JLFET Inverter Tae Jun Ahn <sup>1,2</sup> , Young Baek Kim <sup>2</sup> , and YunSeop Yu <sup>1</sup> <sup>1</sup> Department of Electrical, Electronic and Control Engineering, Hankyong National University, <sup>2</sup> Group for Nano-photonics Convergence Technology, KITECH